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SEMICONDUCTOR PHYSICS

- 112001** First principles study of the Be–C co-doped MgB₂ system (5 pages)
Su Xiyu, Zhi Xiaofen, Hou Qinying, Cheng Wei, and Liu Jiaxue
- 112002** Anisotropic polarization due to electron–phonon interactions in graphene (4 pages)
Li Wuqun and Cao Juncheng
- 112003** Effects of Sn-doping on morphology and optical properties of CdTe polycrystalline films (4 pages)
Li Jin, Yang Linyu, Jian Jikang, Zou Hua, and Sun Yanfei

SEMICONDUCTOR MATERIALS

- 113001** Particular electrical quality of *a*-plane GaN films grown on *r*-plane sapphire by metal-organic chemical vapor deposition (3 pages)
Xu Shengrui, Zhou Xiaowei, Hao Yue, Mao Wei, Zhang Jincheng, Zhang Zhongfen, Bai Lin, Zhang Jinfeng, and Li Zhiming
- 113002** Influence of the distance between target and substrate on the properties of transparent conducting Al–Zr co-doped zinc oxide thin films (4 pages)
Zhang Huafu, Liu Hanfa, Zhou Aiping, and Yuan Changkun
- 113003** Characterization of quaternary AlInGaN epilayers and polarization-reduced InGaN/AlInGaN MQW grown by MOCVD (5 pages)
Liu Naixin, Wang Junxi, Yan Jianchang, Liu Zhe, Ruan Jun, and Li Jinmin
- 113004** Finite element analysis of the temperature field in a vertical MOCVD reactor by induction heating (5 pages)
Li Zhiming, Xu Shengrui, Zhang Jincheng, Chang Yongming, Ni Jinyu, Zhou Xiaowei, and Hao Yue

SEMICONDUCTOR DEVICES

- 114001** InP/InGaAs heterojunction bipolar transistors with different μ -bridge structures (3 pages)
Yu Jinyong, Liu Xinyu, and Xia Yang
- 114002** Fabrication and characteristics of the nc-Si/c-Si heterojunction MAGFET (4 pages)
Zhao Xiaofeng and Wen Dianzhong
- 114003** Memory characteristics of an MOS capacitor structure with double-layer semiconductor and metal heterogeneous nanocrystals (5 pages)
Ni Henan, Wu Liangcai, Song Zhitang, and Hui Chun
- 114004** Structural and electrical characteristics of lanthanum oxide gate dielectric film on GaAs pHEMT technology (4 pages)
Wu Chia-Song and Liu Hsing-Chung
- 114005** Novel lateral IGBT with n-region controlled anode on SOI substrate (4 pages)
Chen Wensuo, Xie Gang, Zhang Bo, Li Zehong, and Li Zhaoji
- 114006** A three-dimensional breakdown model of SOI lateral power transistors with a circular layout (4 pages)
Guo Yufeng, Wang Zhigong, and Sheu Gene
- 114007** Single-mode GaAs/AlGaAs quantum cascade microlasers (4 pages)
Gao Yu, Liu Junqi, Liu Fengqi, Zhang Wei, Zhang Quande, Liu Wanfeng, Li Lu, Wang Lijun, and Wang Zhanguo

(Continued on inside back cover)

- 114008** **A linear array of 980 nm VCSEL and its high temperature operation characteristics** (4 pages)
Zhang Yan, Ning Yongqiang, Wang Ye, Liu Guangyu, Wang Zhenfu, Zhang Xing, Shi Jingjing, Zhang Lisen, Wang Wei, Qin Li, Sun Yanfang, Liu Yun, and Wang Lijun
- 114009** **Estimation of electron mobility of n-doped 4, 7-diphenyl-1, 10-phenanthroline using space-charge-limited currents** (4 pages)
Khizar-ul-Haq, Khan M A, Jiang Xueyin, Zhang Zhilin, Zhang Xiaowen, Zhang Liang, and Li Jun
- 114010** **Working mechanism of a SiC nanotube NO₂ gas sensor** (4 pages)
Ding Ruixue, Yang Yintang, and Liu Lianxi
- 114011** **Modeling and discussion of threshold voltage for a multi-floating gate FET pH sensor** (4 pages)
Shi Zhaoxia and Zhu Dazhong

SEMICONDUCTOR INTEGRATED CIRCUITS

- 115001** **A 10 GHz high-efficiency and low phase-noise negative-resistance oscillator optimized with a virtual loop model** (4 pages)
Wang Xiantai, Jin Zhi, Wu Danyu, Shen Huajun, and Liu Xinyu
- 115002** **An eighth order channel selection filter for low-IF and zero-IF DVB tuner applications** (9 pages)
Zou Liang, Liao Youchun, and Tang Zhangwen
- 115003** **Noise and mismatch optimization for capacitive MEMS readout** (6 pages)
Zhang Chong, Wu Qisong, Yin Tao, and Yang Haigang
- 115004** **A low power high gain UWB LNA in 0.18- μ m CMOS** (5 pages)
Cai Li, Fu Zhongqian, and Huang Lu
- 115005** **Realization of an analog predistortion circuit for RF optical fiber links** (4 pages)
Tian Xuenong, Wang Zhigong, and Li Wei
- 115006** **Design of a DTCTGAL circuit and its application** (6 pages)
Wang Pengjun, Li Kunpeng, and Mei Fengna
- 115007** **A 12-bit 100 MS/s pipelined ADC with digital background calibration** (5 pages)
Zhou Liren, Luo Lei, Ye Fan, Xu Jun, and Ren Junyan
- 115008** **Accurate metamodels of device parameters and their applications in performance modeling and optimization of analog integrated circuits** (7 pages)
Liang Tao, Jia Xinzhang and Chen Junfeng
- 115009** **Circuit design of a novel FPGA chip FDP2008** (6 pages)
Wu Fang, Wang Yabin, Chen Liguang, Wang Jian, Lai Jinmei, Wang Yuan, and Tong Jiarong

SEMICONDUCTOR TECHNOLOGY

- 116001** **Reduction of proximity effect in fabricating nanometer-spaced nanopillars by two-step exposure** (4 pages)
Zhang Yang, Zhang Renping, Han Weihua, Liu Jian, Yang Xiang, Wang Ying, Li Chian Chiu, and Yang Fuhua